

# Nickolai I Klyui

## List of Publications by Year in descending order

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80  
papers

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516215

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525886

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80  
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80  
docs citations

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times ranked

994  
citing authors

#	ARTICLE	IF	CITATIONS
1	Flexible Supercapacitors Based on Polyaniline Arrays Coated Graphene Aerogel Electrodes. <i>Nanoscale Research Letters</i> , 2017, 12, 394.	3.1	67
2	The enhanced field emission from microtips covered by ultrathin layers. <i>Journal of Micromechanics and Microengineering</i> , 1997, 7, 1-6.	1.5	65
3	MOF-derived nitrogen-doped CoO@CoP arrays as bifunctional electrocatalysts for efficient overall water splitting. <i>Electrochimica Acta</i> , 2020, 330, 135210.	2.6	64
4	Porous biomorphic silicon carbide ceramics coated with hydroxyapatite as prospective materials for bone implants. <i>Materials Science and Engineering C</i> , 2016, 68, 143-152.	3.8	54
5	Energy Band Structure and Optical Properties of Wurtzite-Structure Silicon Carbide Crystals. <i>Physica Status Solidi (B): Basic Research</i> , 1990, 162, 477-487.	0.7	40
6	Hierarchical porous ZnO microflowers with ultra-high ethanol gas-sensing at low concentration. <i>Chemical Physics Letters</i> , 2018, 699, 1-7.	1.2	39
7	Electronic band structure and optical properties of cubic silicon carbide crystals. <i>Physica B: Condensed Matter</i> , 1993, 185, 394-399.	1.3	36
8	Silicon solar cells with antireflection diamond-like carbon and silicon carbide films. <i>Solar Energy Materials and Solar Cells</i> , 2002, 72, 597-603.	3.0	34
9	Porous silicon Bragg mirrors on single- and multi-crystalline silicon for solar cells. <i>Renewable Energy</i> , 2013, 55, 79-84.	4.3	28
10	Enhancement of field emission from cathodes with superthin diamond-like carbon films. <i>Applied Surface Science</i> , 1997, 111, 213-217.	3.1	27
11	CoO <sub>x</sub> (OH) <sub>y</sub> /C nanocomposites <i>in situ</i> derived from Na <sub>4</sub> Co <sub>3</sub> (PO <sub>4</sub> ) <sub>2</sub> P <sub>2</sub> O <sub>7</sub> as sustainable electrocatalysts for water splitting. <i>Dalton Transactions</i> , 2018, 47, 15703-15713.	1.6	24
12	Effects of low doping on the improvement of cathode materials Na <sub>3</sub> V <sub>2</sub> M <sub>x</sub> (PO <sub>4</sub> ) <sub>3</sub> (M = Co <sup>2+</sup> , Cu <sup>2+</sup> ; <i>x</i> = 0.01~0.05) for SIBs. <i>Journal of Materials Chemistry A</i> , 2021, 9, 17380-17389.	5.2	24
13	Parameters of the tip arrays covered by low work function layers. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1996, 14, 2130.	1.6	21
14	Properties of plasma enhanced chemical vapor deposition diamond-like carbon films as field electron emitters prepared in different regimes. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1999, 17, 679.	1.6	21
15	Intensive visible photoluminescence of a-C:H:N films. <i>Materials Letters</i> , 1998, 35, 334-338.	1.3	19
16	Facile Synthesis of Hierarchical Tin Oxide Nanoflowers with Ultra-High Methanol Gas Sensing at Low Working Temperature. <i>Nanoscale Research Letters</i> , 2019, 14, 84.	3.1	19
17	Enhancing the cycling stability of the polyaniline hybrids benefited from the hollow manganese dioxide/acetylene black skeleton. <i>Chemical Engineering Journal</i> , 2016, 290, 361-370.	6.6	17
18	Palladium nanoparticles embedded in microporous carbon as electrocatalysts for water splitting in alkaline media. <i>International Journal of Hydrogen Energy</i> , 2021, 46, 21462-21474.	3.8	17

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19	New complex phosphates Cs <sub>3</sub> M <sup>II</sup> Bi(P <sub>2</sub> O <sub>7</sub> ) <sub>2</sub> (M <sup>II</sup> = Ca, Sr) TjETQq 1 0,784314 2274-2284.	1.6	16
20	Electron Energy Structure and Optical Properties of Microcrystalline Silicon. Physica Status Solidi (B): Basic Research, 1989, 155, 723-732.	0.7	15
21	Features of the use of optical reflection from thin porous silicon for detection of organic liquids. Sensors and Actuators B: Chemical, 2017, 242, 1177-1185.	4.0	12
22	Na <sub>4</sub> Ni <sub>3</sub> P <sub>4</sub> O <sub>15</sub> "Ni(OH) <sub>2</sub> core-shell nanoparticles as hybrid electrocatalysts for the oxygen evolution reaction in alkaline electrolytes. Dalton Transactions, 2020, 49, 8226-8237.	1.6	12
23	Properties of gas detonation ceramic coatings and their effect on the osseointegration of titanium implants for bone defect replacement. Ceramics International, 2021, 47, 25425-25439.	2.3	12
24	Characteristic Features of the Electronic Structure of Carbon Films. Physica Status Solidi (B): Basic Research, 1988, 145, 209-217.	0.7	11
25	C-reactive protein detection based on ISFET structure with gate dielectric SiO <sub>2</sub> -CeO <sub>2</sub> . Microelectronic Engineering, 2019, 215, 110993.	1.1	11
26	Bi(nanoparticles)/CN <sub>x</sub> (nanosheets) nanocomposites as high capacity and stable electrode materials for supercapacitors: the role of urea. Dalton Transactions, 2020, 49, 12197-12209.	1.6	11
27	Peculiarities of field emission from silicon carbide films. Applied Surface Science, 2003, 215, 237-241.	3.1	9
28	Influence of deposition conditions on the antireflection properties of diamond-like carbon films for Si-based solar cells. Technical Physics, 2006, 51, 654-658.	0.2	9
29	Nonstoichiometric amorphous silicon carbide films as promising antireflection and protective coatings for germanium in IR spectral range. Optical Materials, 2019, 88, 445-450.	1.7	9
30	Colorimetric analysis of optical reflection from thin porous silicon for detection of organic liquids. Sensors and Actuators B: Chemical, 2019, 280, 102-108.	4.0	9
31	Porous silicon photoluminescence modification by surface treatments and impregnation of carbon based nanoclusters. Physica Status Solidi A, 2003, 197, 355-359.	1.7	8
32	Antireflection properties of diamond-like carbon films on Cd <sub>1-x</sub> Zn <sub>x</sub> Te (x <sup>1/4</sup> 0.04) single crystals. Technical Physics Letters, 2008, 34, 377-380.	0.2	8
33	Effect of H <sup>+</sup> implantation on the optical properties of semi-insulating GaAs crystals in the IR spectral region. Semiconductors, 2017, 51, 305-309.	0.2	8
34	Microraman and microhardness study of nitrogen implanted diamond-like carbon films. Carbon, 1998, 36, 791-794.	5.4	7
35	Effect of oxygen on ion-beam induced synthesis of SiC in silicon. Nuclear Instruments & Methods in Physics Research B, 1999, 147, 256-260.	0.6	7
36	Light emission of the silicon carbide nanoclusters embedded into porous silicon. Materials Science and Engineering C, 2002, 19, 229-231.	3.8	7

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37	Photo-assisted field emission and electro-reflectance modulation investigations of GaN nanorod arrays. <i>Thin Solid Films</i> , 2014, 564, 218-221.	0.8	7
38	Effect of discharge power and silicon content on optical and mechanical properties of carbon-rich amorphous silicon carbide films obtained by PECVD. <i>Journal of Alloys and Compounds</i> , 2019, 801, 285-294.	2.8	7
39	Origin of luminescence in ZnMoO <sub>4</sub> crystals: Insights from spectroscopic studies and electronic structure calculations. <i>Journal of Luminescence</i> , 2019, 211, 127-137.	1.5	7
40	Partial Substitution of Potassium with Sodium in the K <sub>2</sub> Ti <sub>2</sub> (PO <sub>4</sub> ) <sub>3</sub> Langbeinite-Type Framework: Synthesis and Crystalline Structure of K <sub>1.75</sub> Na <sub>0.25</sub> Ti <sub>2</sub> (PO <sub>4</sub> ) <sub>3</sub> . <i>ChemistryOpen</i> , 2018, 7, 504-512.	0.9	6
41	Effect of annealing in zinc vapors on charge trapping properties of ZnSe, ZnSe(Te) and ZnSe(Al) scintillation crystals: Revealing the mechanisms by DFT computational studies. <i>Optical Materials</i> , 2019, 97, 109402.	1.7	6
42	Mn <sup>2+</sup> luminescence of Gd(Zn,Mg)B <sub>5</sub> O <sub>10</sub> pentaborate under high pressure. <i>Dalton Transactions</i> , 2020, 49, 14268-14279.	1.6	6
43	High efficient solar cells and modules based on diamond-like carbon film - multicrystalline Si structures. <i>Semiconductor Physics, Quantum Electronics and Optoelectronics</i> , 2003, 6, 197-201.	0.3	6
44	Distinctive features of time-resolved photoluminescence of porous silicon coated with a layer of diamondlike carbon. <i>Technical Physics</i> , 1998, 43, 423-426.	0.2	5
45	Possibility of a double-well potential formation in diamondlike amorphous carbon. <i>Physical Review B</i> , 1998, 58, 3526-3528.	1.1	5
46	Electron Field Emission from Undoped and Doped DLC Films. <i>Materials Research Society Symposia Proceedings</i> , 1999, 558, 577.	0.1	5
47	Raman spectroscopy and microhardness of ion-implanted a-C:H-films. <i>Ceramics International</i> , 2000, 26, 29-32.	2.3	5
48	Micro-Raman study of high pressure induced graphite-diamond phase-structural transformation: The role of a nitrogen containing precursor. <i>Journal of Applied Physics</i> , 2000, 88, 4875.	1.1	5
49	Ion-plasma treatment of Cd <sub>1-x</sub> Zn <sub>x</sub> Te (x ≈ 0.04) single crystals and application of antireflection diamond-like carbon films. <i>Technical Physics</i> , 2012, 57, 1121-1126.	0.2	4
50	Application of diamond-like carbon films to increase transmission of semi-insulating GaAs crystals in the IR spectral range. <i>Technical Physics Letters</i> , 2012, 38, 609-612.	0.2	4
51	Photoluminescence of porous-silicon/diamondlike-carbon-film structures subjected to rapid thermal annealing. <i>Technical Physics Letters</i> , 1999, 25, 304-306.	0.2	3
52	Increasing the degradation resistance of semi-insulating gallium arsenide crystals by plasma processing. <i>Technical Physics Letters</i> , 2012, 38, 1016-1019.	0.2	3
53	Electroreflectance study of the effect of <sup>137</sup> I radiation on the optical properties of epitaxial GaN films. <i>Semiconductors</i> , 2012, 46, 302-305.	0.2	3
54	Improvement in the degradation resistance of silicon nanostructures by the deposition of diamond-like carbon films. <i>Semiconductors</i> , 2015, 49, 1030-1034.	0.2	3

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55	Effect of Plasma, RF, and RIE Treatments on Properties of Double-Sided High Voltage Solar Cells with Vertically Aligned p-n Junctions. International Journal of Photoenergy, 2016, 2016, 1-8.	1.4	3
56	EPR and Raman study of silicon layers obtained by gas detonation spraying. Materials Science in Semiconductor Processing, 2017, 71, 232-239.	1.9	3
57	Scheelite-related $M_{1-x}Bi_xV_{1-x}Mo_xO_4$ ( $M^{2+}$ = Ca, Sr) solid solution-based photoanodes for enhanced photoelectrochemical water oxidation. Dalton Transactions, 2020, 49, 2345-2355.	1.6	3
58	Improvement of Solar Cells Efficiency and Radiation Stability by Deposition of Diamond-Like Carbon Films. , 2011, , .		3
59	SiC Buried Layer Formation Induced by Ion Implantation. Solid State Phenomena, 1995, 47-48, 211-216.	0.3	2
60	Influence of nitrogen on the optical and mechanical properties of diamond-like carbon films. Technical Physics Letters, 1998, 24, 408-409.	0.2	2
61	Electron Processes in Low-Dimension Porous Si-Fulleren System: Photoluminescence Study. Molecular Crystals and Liquid Crystals, 1998, 324, 13-18.	0.3	2
62	Photoluminescence of porous silicon layers formed in ion-implanted silicon wafers. Technical Physics Letters, 2000, 26, 944-946.	0.2	2
63	Improvement of radiation stability of semi-insulating gallium arsenide crystals by deposition of diamond-like carbon films. Optical Materials, 2016, 62, 372-377.	1.7	2
64	Modification of Optical Properties of a-C:H and a-C:H:N Films Subjected to Ion Implantation and UV Treatment. Molecular Crystals and Liquid Crystals, 1998, 324, 19-24.	0.3	1
65	Photoluminescent properties of nitrogen-containing DLC films. Ceramics International, 2000, 26, 411-414.	2.3	1
66	Optical properties of diamond-like carbon films subjected to ultraviolet irradiation. Semiconductor Physics, Quantum Electronics and Optoelectronics, 2008, 11, 396-399.	0.3	1
67	Electronic band structure and optical properties of cubic silicon carbide crystals. , 1993, , 394-399.		1
68	Interaction of calcium phosphate and CaO (CaCO <sub>3</sub> ) while their disposing on the titanium surface under gas detonation conditions. Reports National Academy of Science of Ukraine, 2017, , 66-72.	0.0	1
69	Investigation of Ion Implanted Silicon by Electroreflectance Spectroscopy. Physica Status Solidi A, 1989, 112, 805-810.	1.7	0
70	Investigation of multilayer SOI structures by electroreflectance spectroscopy. Materials Letters, 1993, 18, 137-140.	1.3	0
71	Oxygen plasma treatment of Gd <sub>1-x</sub> Ba <sub>x</sub> Cu <sub>1-x</sub> O high-T <sub>c</sub> superconducting films. Physica C: Superconductivity and Its Applications, 1994, 235-240, 1211-1212.	0.6	0
72	Oxygen plasma treatment effect on optical properties of GdBa <sub>2</sub> Cu <sub>3</sub> O <sub>7-x</sub> high-T <sub>c</sub> superconducting films. Thin Solid Films, 1994, 238, 119-122.	0.8	0

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73	Field Electron Emission From Silicon Tip Arrays Coated With Nitrogen Doped DLC Films.. , 1997, , .		0
74	Influence of oxygen on the ion-beam synthesis of silicon carbide buried layers in silicon. Semiconductors, 1998, 32, 1261-1265.	0.2	0
75	Properties of PE-CVD DLC films as field electron emitters prepared in different regimes. , 0, , .		0
76	Diagnostics of nitrogen-implanted diamond-like carbon films by optical and microhardness measurements. , 1998, 3359, 339.		0
77	Optical study of the influence of oxygen on the synthesis of SiC-buried layer in Cz-Si and Fz-Si. , 1998, 3359, 375.		0
78	Evaluation of the Interface Properties of Recombination Sensors From the Measurement of Capacitance-Voltage Characteristics. , 2019, , .		0
79	Micro-Raman study of CN <sub>x</sub> composites subjected to high pressure treatment. Semiconductor Physics, Quantum Electronics and Optoelectronics, 1999, 2, 13-18.	0.3	0
80	Rietveld refinement of the langbeinite-type phosphate $K_{2}Ni_{0.5}Hf_{1.5}(PO_{4})_{3}$ . Acta Crystallographica Section E: Crystallographic Communications, 2020, 76, 1634-1637.	0.2	0